

# Agilent MSA-0786 Cascadable Silicon Bipolar MMIC Amplifier

**Data Sheet** 

## **Description**

The MSA-0786 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a low cost, surface mount plastic package. This MMIC is designed for use as a general purpose  $50~\Omega$  gain block. Applications include narrow and broad band IF and RF amplifiers in commercial and industrial applications.

The MSA-series is fabricated using Agilent's 10 GHz f<sub>T</sub>, 25 GHz f<sub>MAX</sub>, silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

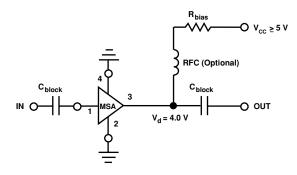
### 86 Plastic Package



### **Features**

- Cascadable 50  $\Omega$  Gain Block
- Low Operating Voltage: 4.0 V Typical  $V_d$
- 3 dB Bandwidth: DC to 2.0 GHz
- 12.5 dB Typical Gain at 1.0 GHz
- Unconditionally Stable (k>1)
- Surface Mount Plastic Package
- Tape-and-Reel Packaging Option Available
- Lead-free Option Available

## **Typical Biasing Configuration**



## MSA-0786 Absolute Maximum Ratings

Parameter	Absolute Maximum <sup>[1]</sup>
Device Current	60 mA
Power Dissipation <sup>[2,3]</sup>	275 mW
RF Input Power	+13 dBm
Junction Temperature	150°C
Storage Temperature	−65 to 150°C

Thermal Resistance <sup>[2]</sup> :	
$\theta_{\rm jc}=120^{\circ}{ m C/W}$	

#### Notes

- 1. Permanent damage may occur if any of these limits are exceeded.
- 2.  $T_{CASE} = 25$ °C.
- 3. Derate at 8.3 mW/°C for  $T_{\rm C} > 117 ^{\circ}{\rm C}.$

## Electrical Specifications [1], $T_A = 25^{\circ}C$

Symbol	<b>Parameters and Test Conditions:</b>	Units	Min.	Тур.	Max.	
GP	Power Gain $( S_{21} ^2)$ f = 0.1 GHz		dB		13.5	
		f = 1.0  GHz		10.5	12.5	
ΔGP	Gain Flatness	f = 0.1 to 1.3 GHz	dB		±0.7	
f <sub>3 dB</sub>	3 dB Bandwidth		GHz		2.0	
VSWR	Input VSWR	f = 0.1 to 2.5 GHz			1.7:1	
VSWIL	Output VSWR	f = 0.1  to  2.5  GHz			1.7:1	
NF	$50~\Omega$ Noise Figure	f = 1.0 GHz	dB		5.0	
P <sub>1 dB</sub>	Output Power at 1 dB Gain Compression	f = 1.0 GHz	dBm		5.5	
IP3	Third Order Intercept Point	f = 1.0  GHz	dBm		19.0	
$t_{\mathrm{D}}$	Group Delay	f = 1.0 GHz	psec		150	
Vd	Device Voltage		V	3.2	4.0	4.8
dV/dT	Device Voltage Temperature Coefficient		mV/°C		-7.0	

#### Note

## **Ordering Information**

Part Numbers	No. of Devices	Comments		
MSA-0786-BLK	100	Bulk		
MSA-0786-BLKG	100	Bulk		
MSA-0786-TR1	1000	7" Reel		
MSA-0786-TR1G	1000	7" Reel		

**Note:** Order part number with a "G" suffix if lead-free option is desired.

<sup>1.</sup> The recommended operating current range for this device is 15 to 40 mA. Typical performance as a function of current is on the following page.

MSA-0786 Typical Scattering Parameters	$(\mathbf{Z}_{\mathbf{O}} = 50 \ \Omega, \mathbf{T}_{\mathbf{O}})$	$\Gamma_{\rm A}$ = 25°C, $I_{\rm d}$ = 22 mA)	
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Freq.	S <sub>11</sub>			$S_{21}$	$S_{21}$		$\mathbf{S}_{12}$		$\mathbf{S}_{12}$			2
GHz	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang		
0.1	.05	175	13.5	4.74	174	-18.7	.116	1	.14	-12		
0.2	.05	174	13.4	4.71	169	-18.7	.117	3	.14	-22		
0.4	.04	167	13.3	4.64	158	-18.4	.120	4	.15	-44		
0.6	.04	175	13.1	4.52	148	-18.3	.122	7	.16	-65		
0.8	.05	-156	12.9	4.39	138	-18.0	.126	8	.17	-84		
1.0	.06	-134	12.6	4.25	127	-17.5	.134	10	.18	-102		
1.5	.08	-142	11.6	3.79	103	-16.6	.148	9	.21	-139		
2.0	.15	-159	10.5	3.34	80	-15.7	.164	7	.23	-164		
2.5	.25	-176	9.2	2.89	63	-15.1	.176	5	.24	174		
3.0	.33	166	7.8	2.45	44	-14.7	.185	1	.24	159		
3.5	.41	150	6.5	2.11	27	-14.9	.179	-5	.24	149		
4.0	.49	137	5.2	1.82	12	-15.1	.177	<b>-</b> 9	.23	145		
5.0	.60	116	3.0	1.41	-14	-15.4	.169	-14	.26	145		

## Typical Performance, $T_A = 25^{\circ}C$

(unless otherwise noted)

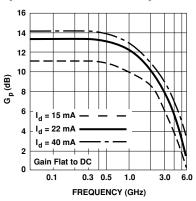


Figure 1. Typical Power Gain vs. Frequency.

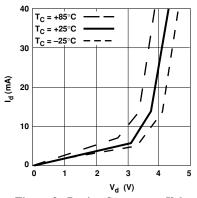


Figure 2. Device Current vs. Voltage.

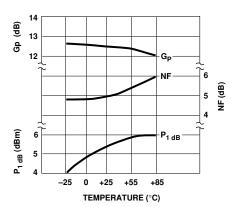


Figure 3. Output Power at 1 dB Gain Compression, NF and Power Gain vs. Case Temperature, f = 1.0 GHz,  $I_d$  = 22 mA.

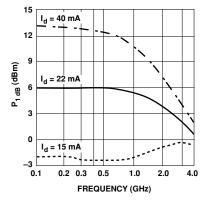


Figure 4. Output Power at 1 dB Gain Compression vs. Frequency.

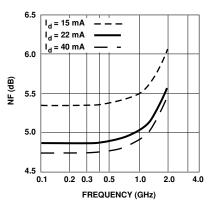
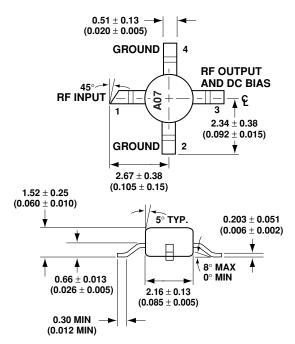


Figure 5. Noise Figure vs. Frequency.

## **86 Plastic Package Dimensions**



**DIMENSIONS ARE IN MILLIMETERS (INCHES)** 

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Data subject to change.

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